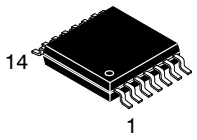
Low Voltage Quad 2-Input NAND Schmitt Trigger

74LVX132



TSSOP−14 WB
CASE 948G

General Description

The LVX132 contains four 2−input NAND Schmitt Trigger Gates. The pin configuration and function are the same as the LVX00 but the inputs have hysteresis between the positive−going and negative−going input thresholds, which are capable of transforming slowly changing input signals into sharply defined, jitter−free output signals, thus providing greater noise margins than conventional gates.

The inputs tolerate voltages up to 6.5 V allowing the interface of 5 V systems to 3 V systems.

Features

- Input Voltage Level Translation from 5 V to 3 V
- Ideal for Low Power/Low Noise 3.3 V Applications
- Guaranteed Simultaneous Switching Noise Level and Dynamic Threshold Performance
- Pb−Free, Halogen Free/BFR Free and RoHS Compliant

Logic Diagram

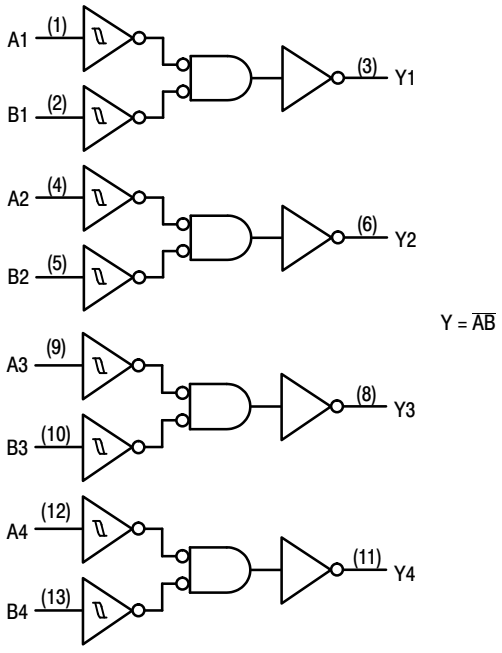
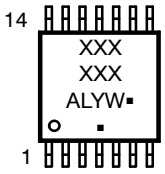


Figure 1. Logic Diagram

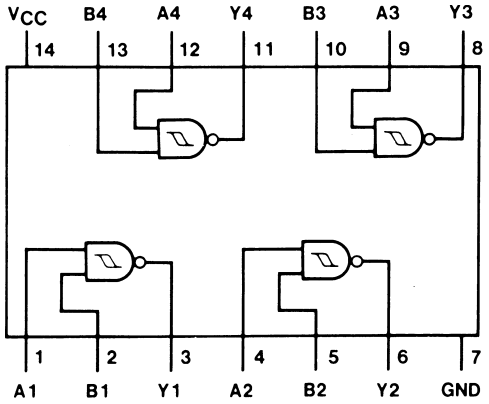
MARKING DIAGRAM



XXXXX = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb−Free Package

(Note: Microdot may be in either location)

CONNECTION DIAGRAM



PIN DESCRIPTION

Pin Names	Description
A_n, B_n	Inputs
Y_n	Outputs

ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

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MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	−0.5 to +6.5	V
I_{IK}	DC Input Diode Current, V_I = −0.5 V	−20	mA
V_I	DC Input Voltage	−0.5 to +6.5	V
I_{OK}	DC Output Diode Current V_O = −0.5 V V_O = V_{CC} + 0.5 V	 −20 +20	mA
V_O	DC Output Voltage	−0.5 to V_{CC} + 0.5	V
I_O	DC Output Source or Sink Current	±25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	±50	mA
T_{STG}	Storage Temperature	−65 to +150	°C
P_D	Power Dissipation	833	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS (Note 1)

Symbol	Parameter	Min	Max	Unit
V_{CC}	Supply Voltage	2.0	3.6	V
V_I	Input Voltage	0	5.5	V
V_O	Output Voltage	0	V_{CC}	V
T_A	Operating Temperature	−40	+85	°C
$\Delta t / \Delta V$	Input Rise and Fall Time	0	100	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	V_{CC} (V)	Conditions		T_A = 25°C			T_A = −40°C to +85°C		Unit
					Min	Typ	Max	Min	Max	
V_{t+}	Positive Threshold	3.0			–	–	2.2	–	2.2	V
V_{t-}	Negative Threshold	3.0			0.9	–	–	0.9	–	V
V_H	Hysteresis	3.0			0.3	–	1.2	0.3	1.2	V
V_{OH}	HIGH Level Output Voltage	2.0	V_{IN} = V_{IL} or V_{IH}	I_{OH} = −50 μA	1.9	2.0	–	1.9	–	V
		3.0		I_{OH} = −50 μA	2.9	3.0	–	2.9	–	
		3.0		I_{OH} = −4 mA	2.58	–	–	2.48	–	
V_{OL}	LOW Level Output Voltage	2.0	V_{IN} = V_{IL} or V_{IH}	I_{OL} = 50 μA	–	0.0	0.1	–	0.1	V
		3.0		I_{OL} = 50 μA	–	0.0	0.1	–	0.1	
		3.0		I_{OL} = 4 mA	–	–	0.36	–	0.44	
I_{IN}	Input Leakage Current	3.6	V_{IN} = 5.5 V or GND		–	–	±0.1	–	±1.0	μA
I_{CC}	Quiescent Supply Current	3.6	V_{IN} = V_{CC} or GND		–	–	2.0	–	20.0	μA

NOISE CHARACTERISTICS (Note 2)

Symbol	Parameter	V_{CC} (V)	Conditions	T_A = 25°C		Unit
				Typ	Limit	
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	C_L = 50 pF	0.3	0.5	V
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	C_L = 50 pF	−0.3	−0.5	V
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3	C_L = 50 pF	–	2.0	V
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3	C_L = 50 pF	–	0.8	V

2. Input t_r = t_f = 3 ns

AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	V_{CC} (V)	Conditions	T_A = 25°C			T_A = −40°C to +85°C		Unit
				Min	Typ	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay Time	2.7	C_L = 15 pF	–	7.0	11.5	1.0	13.0	ns
			C_L = 50 pF	–	10.5	16.0	1.0	18.7	
		3.3 ±0.3	C_L = 15 pF	–	6.1	10.6	1.0	12.5	ns
			C_L = 50 pF	–	9.0	15.4	1.0	17.5	
t_{OSLH}, t_{OSHL}	Output to Output Skew (Note 3)	2.7	C_L = 50 pF	–	–	1.5	–	1.5	ns
		3.3		–	–	1.5	–	1.5	

3. Parameter guaranteed by design t_{OSLH} = $|t_{PLHm} - t_{PLHn}|$, t_{OSHL} = $|t_{PHLm} - t_{PHLn}|$

CAPACITANCE

Symbol	Parameter	Conditions	T_A = 25°C			T_A = −40°C to +85°C		Unit
			Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		–	4	10	–	10	pF
C_{PD}	Power Dissipation Capacitance (Note 4)		–	18	–	–	–	pF

4. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:
$I_{CC(opr.)}$ = (C_{PD} × V_{CC} × f_{IN} × I_{CC}) / 6 (per Gate)

ORDERING INFORMATION

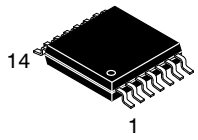
Device Order Number	Top Marking	Package Type	Shipping†
74LVX132MTCX	LVX 132	TSSOP−14 WB (Pb−Free, Halide Free)	2500 units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

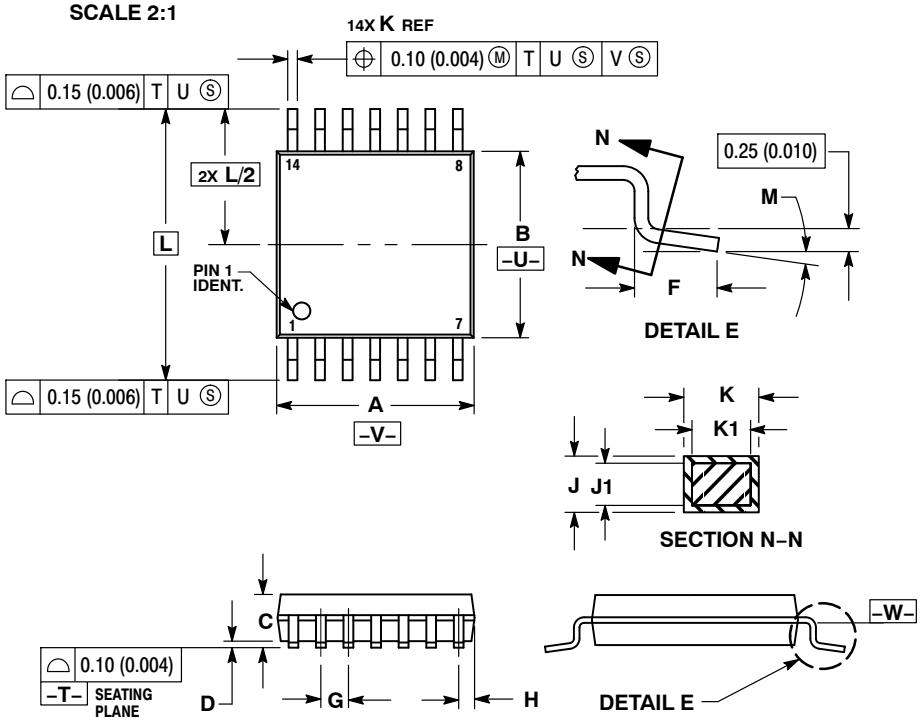
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

TSSOP−14 WB
CASE 948G
ISSUE C

DATE 17 FEB 2016



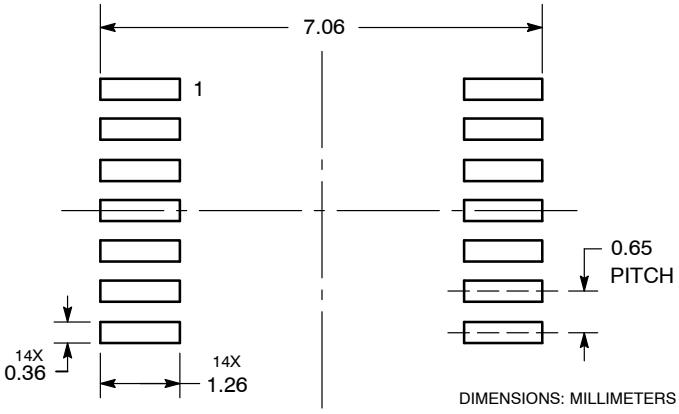
SCALE 2:1



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE −W−.

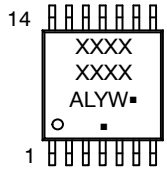
	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	−−−	1.20	−−−	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0 °	8 °	0 °	8 °

SOLDERING FOOTPRINT



DIMENSIONS: MILLIMETERS

GENERIC MARKING DIAGRAM*



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

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